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November 2013

## FDB031N08

# N-Channel PowerTrench $^{\mathbb{R}}$ MOSFET 75 V, 235 A, 3.1 m $_{\Omega}$

#### **Features**

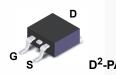
- $R_{DS(on)}$  = 2.4 m $\Omega$  (Typ.) @  $V_{GS}$  = 10 V,  $I_D$  = 75 A
- · Fast Switching Speed
- · Low Gate Charge
- High Performance Trench Technology for Extremely Low  $R_{DS(on)}$
- · High Power and Current Handling Capability
- RoHS Compliant

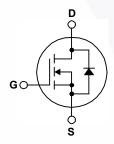
#### Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench® process that has been tailored to minimize the on-state resistance while maintaining superior switching performance.

### **Applications**

- · Synchronous Rectification for ATX / Server / Telecom PSU
- · Battery Protection Circuit
- · Motor Drives and Uninterruptible Power Supplies





#### **MOSFET Maximum Ratings** T<sub>C</sub> = 25°C unless otherwise noted.

Symbol		Parameter	FDB031N08	Unit
V <sub>DSS</sub>	Drain to Source Voltage	75	V	
V <sub>GSS</sub>	Gate to Source Voltage	±20	V	
	Drain Current - Co	235	Α	
I <sub>D</sub>	- C	ontinuous (T <sub>C</sub> = 100°C, Silicon Limited)	165	A
	- C	120	A	
$I_{DM}$	Drain Current	- Pulsed (N	Note 1) 940	А
E <sub>AS</sub>	Single Pulsed Avalanche Ener	gy (N	Note 2) 1995	mJ
dv/dt	Peak Diode Recovery dv/dt	1)	Note 3) 5.5	V/ns
D	Dawer Dissipation	$(T_C = 25^{\circ}C)$	375	W
Power Dissipation		- Derate Above 25°C	2.5	W/°C
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Tempe	-55 to +175	°C	
TL	Maximum Lead Temperature for	or Soldering, 1/8" from Case for 5 Secon	ds 300	°C

#### **Thermal Characteristics**

Symbol	Parameter	FDB031N08	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	0.4	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient, Max.	62.5	C/VV

## **Package Marking and Ordering Information**

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FDB031N08	FDB031N08	D <sup>2</sup> -PAK	Tape and Reel	330 mm	24 mm	800 units

## **Electrical Characteristics** $T_C = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Charac	cteristics					
$BV_{DSS}$	Drain to Source Breakdown Voltage	$I_D = 250 \mu A, V_{GS} = 0 V, T_C = 25^{\circ}C$	75	-	-	V
ΔBV <sub>DSS</sub> / ΔT <sub>J</sub>	Breakdown Voltage Temperature Coefficient	$I_D$ = 250 μA, Referenced to 25°C	-	0.05	-	V/°C
1	Zero Gate Voltage Drain Current	$V_{DS} = 75 \text{ V}, V_{GS} = 0 \text{ V}$	-	-	1	μA
IDSS	Zero Gate Voltage Drain Current	$V_{DS} = 75 \text{ V}, T_{C} = 150^{\circ}\text{C}$	-	-	500	μΑ
I <sub>GSS</sub>	Gate to Body Leakage Current	V <sub>GS</sub> = ±20 V, V <sub>DS</sub> = 0 V	-	-	±100	nA

#### **On Characteristics**

V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \mu\text{A}$	2.5	3.5	4.5	V
R <sub>DS(on)</sub>	Static Drain to Source On Resistance	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 75 A	-	2.4	3.1	$m\Omega$
9 <sub>FS</sub>	Forward Transconductance	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 75 A	ı	180	1	S

## **Dynamic Characteristics**

C <sub>iss</sub>	Input Capacitance	V 05.V.V 0.V		-	11400	15160	pF
C <sub>oss</sub>	Output Capacitance	$V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V},$ f = 1 MHz		-	1360	1810	pF
C <sub>rss</sub>	Reverse Transfer Capacitance	1 – 1 101112		-\	595	800	pF
Q <sub>g(tot)</sub>	Total Gate Charge at 10V	V <sub>DS</sub> = 60 V, I <sub>D</sub> = 75 A,		-	169	220	nC
$Q_{gs}$	Gate to Source Gate Charge	V <sub>GS</sub> = 10 V		-	60	-	nC
$Q_{gd}$	Gate to Drain "Miller" Charge	(Note	4)	-	47	-	nC

## **Switching Characteristics**

t <sub>d(on)</sub>	Turn-On Delay Time		-	230	470	ns
t <sub>r</sub>		$V_{DD} = 37.5 \text{ V}, I_D = 75 \text{ A},$	-	191	392	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	$R_G = 25 \Omega, V_{GS} = 10 V$	-	335	680	ns
t <sub>f</sub>	Turn-Off Fall Time	(Note 4)	-	121	252	ns

#### **Drain-Source Diode Characteristics**

I <sub>S</sub>	Maximum Continuous Drain to Source Diode Forward Current		-	-	235	Α
I <sub>SM</sub>	Maximum Pulsed Drain to Source Diode Forward Current		-	-	940	Α
$V_{SD}$	Drain to Source Diode Forward Voltage	V <sub>GS</sub> = 0 V, I <sub>SD</sub> = 75 A	-	-	1.3	V
t <sub>rr</sub>	Reverse Recovery Time	V <sub>GS</sub> = 0 V, I <sub>SD</sub> = 75 A,	-	53	-	ns
$Q_{rr}$	Reverse Recovery Charge	dI <sub>F</sub> /dt = 100 A/μs	-	77	_	nC

#### Notos:

- 1. Repetitive rating: pulse-width limited by maximum junction temperature.
- 2. L = 0.71 mH, I $_{AS}$  = 75 A, V $_{DD}$  = 50 V, R $_{G}$  = 25  $\Omega$ , starting T $_{J}$  = 25°C.
- 3. I\_{SD}  $\leq$  75 A, di/dt  $\leq$  200 A/µs, V\_DD  $\leq$  BV\_DSS, starting T\_J = 25°C.
- 4. Essentially independent of operating temperature typical characteristics.

### **Typical Performance Characteristics**

Figure 1. On-Region Characteristics

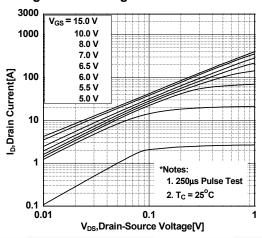


Figure 3. On-Resistance Variation vs.

Drain Current and Gate Voltage

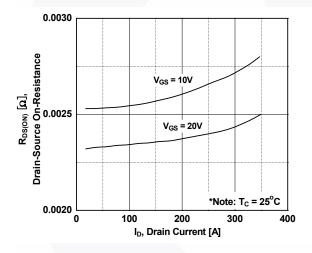


Figure 5. Capacitance Characteristics

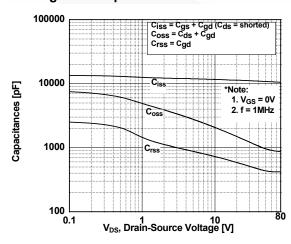


Figure 2. Transfer Characteristics

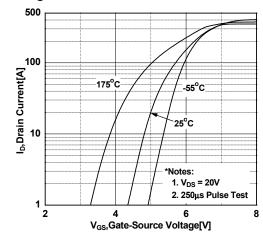


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

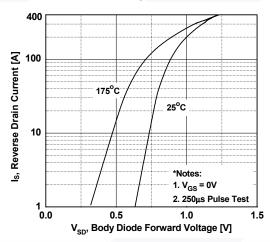
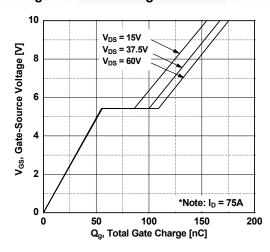


Figure 6. Gate Charge Characteristics



## **Typical Performance Characteristics** (Continued)

Figure 7. Breakdown Voltage Variation vs. Temperature

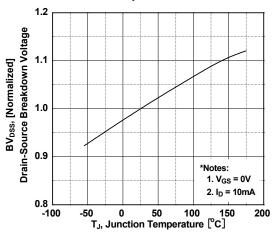


Figure 8. On-Resistance Variation vs. Temperature

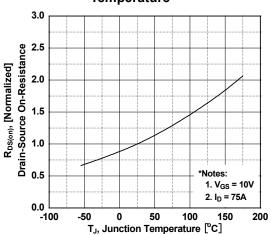
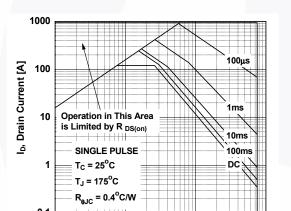


Figure 9. Maximum Safe Operating Area



V<sub>DS</sub>, Drain-Source Voltage [V]

Figure 10. Maximum Drain Current vs. Case Temperature

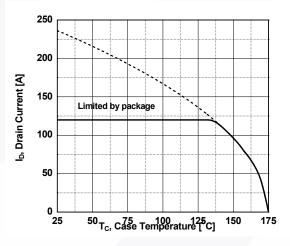
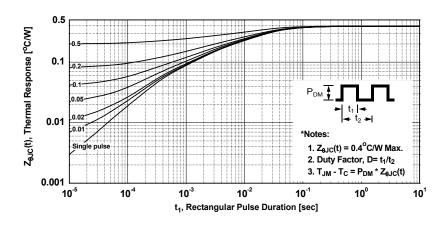


Figure 11. Transient Thermal Response Curve

100



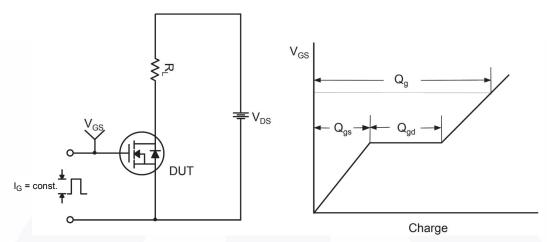


Figure 12. Gate Charge Test Circuit & Waveform

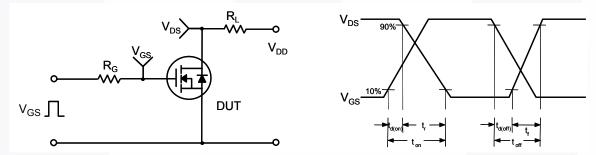


Figure 13. Resistive Switching Test Circuit & Waveforms

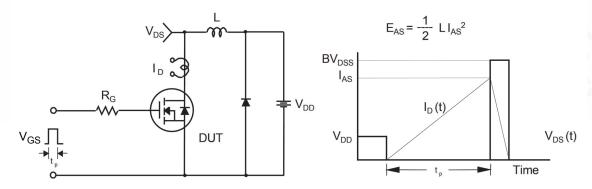


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms

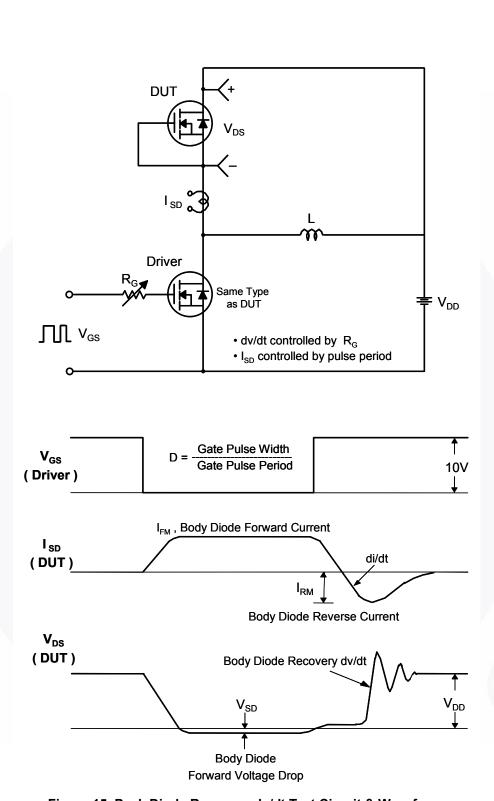


Figure 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms

#### **Mechanical Dimensions**

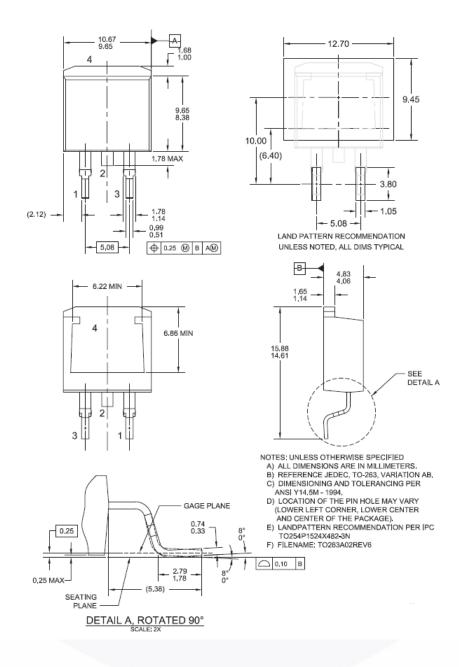


Figure 16. TO263 (D<sup>2</sup>PAK), Molded, 2-Lead, Surface Mount

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